# MOSFET – Power, Single, N-Channel, TSOP-6 30 V, 7.0 A

#### Features

- Low R<sub>DS(on)</sub>
- Low Gate Charge
- NV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- Pb–Free Package is Available

#### Applications

- Load Switch
- Notebook PC
- Desktop PC

#### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Ratin	Symbol	Value	Unit		
Drain-to-Source Voltage			V <sub>DSS</sub>	30	V
Gate-to-Source Voltage			V <sub>GS</sub>	±20	V
Continuous Drain	Steady	$T_A = 25^{\circ}C$	I <sub>D</sub>	5.0	А
Current (Note 1)	State	T <sub>A</sub> = 85°C		3.6	
	t ≤ 10 s	T <sub>A</sub> = 25°C		7.0	
Power Dissipation (Note 1)	Steady State	$T_A = 25^{\circ}C$	P <sub>D</sub>	1.0	W
	t ≤ 10 s			2.0	
Continuous Drain	Steady	$T_A = 25^{\circ}C$	I <sub>D</sub>	3.5	А
Current (Note 2)	State	T <sub>A</sub> = 85°C		2.5	
Power Dissipation (Note 2)		$T_A = 25^{\circ}C$	PD	0.5	W
Pulsed Drain Current	$t_p$ = 10 $\mu$ s, V <sub>GS</sub> =10V		I <sub>DM</sub>	45	А
Pulsed Drain Current	t <sub>p</sub> = 30 μ	s, V <sub>GS</sub> =5V	I <sub>D</sub>	30	А
Operating Junction and Storage Temperature			T <sub>J</sub> , T <sub>STG</sub>	–55 to 150	°C
Source Current (Body Diode)			۱ <sub>S</sub>	2.0	Α
Single Pulse Drain–to–Source Avalanche Energy (V <sub>DD</sub> = 30 V, I <sub>L</sub> = 10.4 A, V <sub>GS</sub> = 10 V, L = 1.0 mH, R <sub>G</sub> = 25 $\Omega$ )			EAS	54	mJ
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL RESISTANCE RATINGS

Rating	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)	$R_{\theta JA}$	125	°C/W
Junction-to-Ambient – t $\leq$ 10 s (Note 1)	$R_{\theta JA}$	62.5	
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	248	

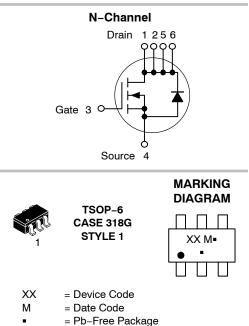
1. Surface-mounted on FR4 board using 1 inch sq pad size (Cu area = 1.127 in sq [1 oz] including traces).



## **ON Semiconductor®**

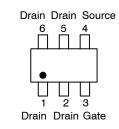
#### http://onsemi.com

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> TYP	I <sub>D</sub> MAX	
30 V	21.5 mΩ @ 10 V	7.0 A	
	30 V 30 mΩ @ 4.5 V		



#### **PIN ASSIGNMENT**

(Note: Microdot may be in either location)



#### **ORDERING INFORMATION**

See detailed ordering and shipping information ion page 6 of this data sheet.

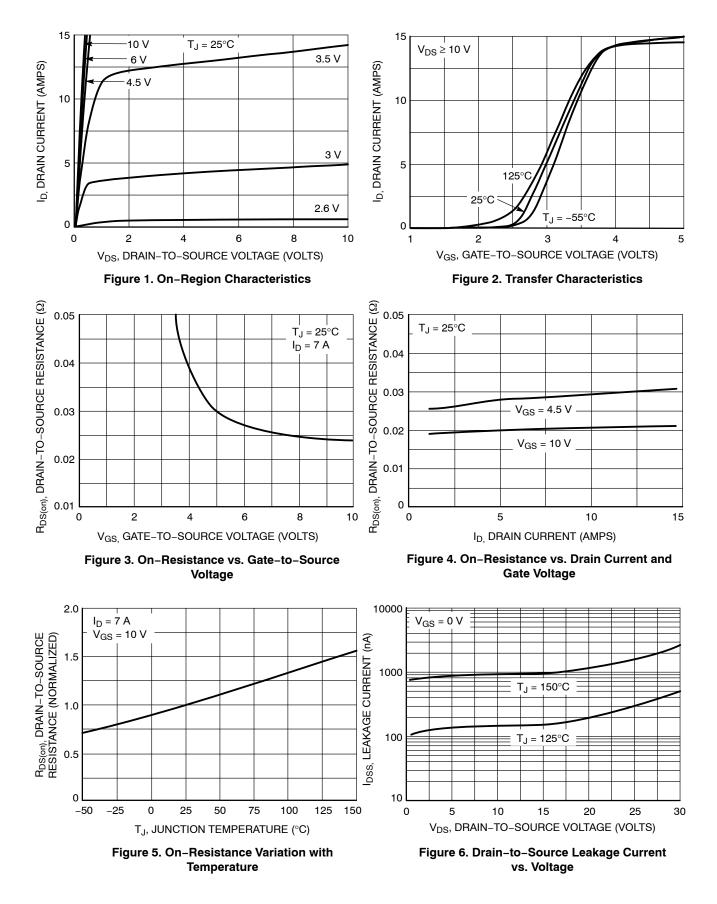
2. Surface-mounted on FR4 board using the minimum recommended pad size (Cu area = 0.0773 in sq).

### **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = $25^{\circ}C$ unless otherwise noted)

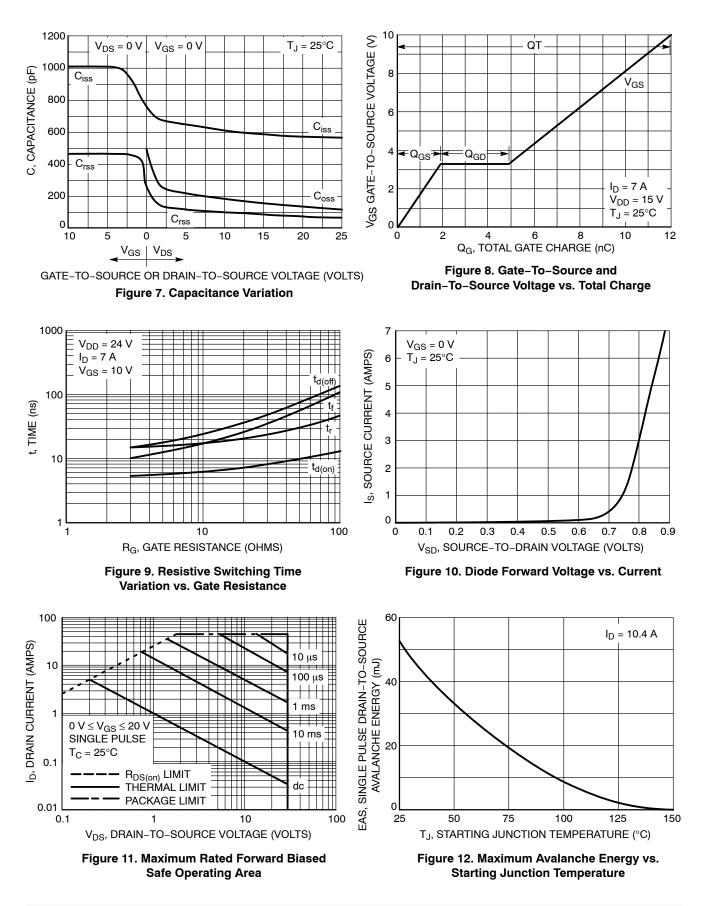
Characteristic	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V <sub>(BR)DSS</sub>	$V_{GS}$ = 0 V, $I_D$ = 250 $\mu$ A		30			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V <sub>(BR)DSS</sub> /T <sub>J</sub>				18.4		mV/°C
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{GS} = 0 V_{.}$	T <sub>J</sub> = 25°C			1.0	μA
		V <sub>GS</sub> = 0 V, V <sub>DS</sub> = 24 V	T <sub>J</sub> = 125°C			10	1
Gate-to-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> = 0 V, V <sub>0</sub>	<sub>GS</sub> = ±20 V			±100	nA
ON CHARACTERISTICS (Note 3)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	V <sub>GS</sub> = V <sub>DS</sub> , I	<sub>D</sub> = 250 μA	1.0		3.0	V
Negative Threshold Temperature Coefficient	V <sub>GS(TH)</sub> /T <sub>J</sub>				5.7		mV/°C
Drain-to-Source On Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 7.0 A			21.5	25	mΩ
		V <sub>GS</sub> = 4.5 V,	I <sub>D</sub> = 6.0 A		30	35	1
Forward Transconductance	<b>9</b> FS	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 7.0 A			30		S
CHARGES, CAPACITANCES AND GATE RE	SISTANCE						
Input Capacitance	C <sub>ISS</sub>	V <sub>GS</sub> = 0 V, f = 1.0 MHz, V <sub>DS</sub> = 24 V			560		pF
Output Capacitance	C <sub>OSS</sub>				115		1
Reverse Transfer Capacitance	C <sub>RSS</sub>				75		
Total Gate Charge	Q <sub>G(TOT)</sub>	V <sub>GS</sub> = 10 V, V <sub>DS</sub> = 15 V, I <sub>D</sub> = 7.0 A			12		nC
Threshold Gate Charge	Q <sub>G(TH)</sub>				0.85		1
Gate-to-Source Charge	Q <sub>GS</sub>				1.9		1
Gate-to-Drain Charge	Q <sub>GD</sub>				3.0		1
Total Gate Charge	Q <sub>G(TOT)</sub>	V <sub>GS</sub> = 4.5 V, V <sub>DS</sub> = 15 V, I <sub>D</sub> = 7.0 A			6.0		nC
Threshold Gate Charge	Q <sub>G(TH)</sub>				0.8		1
Gate-to-Source Charge	Q <sub>GS</sub>				1.85		1
Gate-to-Drain Charge	Q <sub>GD</sub>				3.0		1
Gate Resistance	R <sub>G</sub>				2.8		Ω
SWITCHING CHARACTERISTICS (Note 4)							
Turn-On Delay Time	t <sub>d(ON)</sub>				6.0		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = 10 V, V	/pc = 24 V		15		1
Turn-Off Delay Time	t <sub>d(OFF)</sub>	$I_{\rm D} = 7.0 \rm{A}, \rm{F}$	$R_{\rm G} = 3.0 \ \Omega$		18		1
Fall Time	t <sub>f</sub>	1			4.0		1
DRAIN – SOURCE DIODE CHARACTERIST	CS						
Forward Diode Voltage	V <sub>SD</sub>	V <sub>GS</sub> = 0 V,	T <sub>J</sub> = 25°C		0.78	1.0	V
5		V <sub>GS</sub> = 0 V, I <sub>S</sub> = 2.0 A	T <sub>J</sub> = 125°C		0.63		_
Reverse Recovery Time	t <sub>RR</sub>	V <sub>GS</sub> = 0 V dI <sub>S</sub> /dt = 100 A/μs, I <sub>S</sub> = 2.0 A			15		ns
Charge Time	ta				9.0	1	1
Discharge Time	t <sub>b</sub>				6.0		-
Reverse Recovery Charge	Q <sub>RR</sub>				8.0		nC

performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. Pulse Test: pulse width  $\leq 300 \ \mu$ s, duty cycle  $\leq 2\%$ . 4. Switching characteristics are independent of operating junction temperatures.

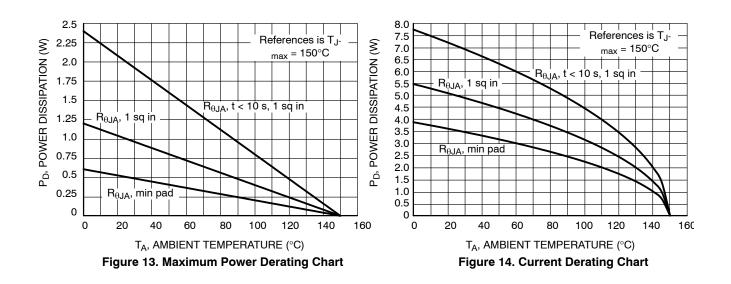
#### **TYPICAL PERFORMANCE CURVES**

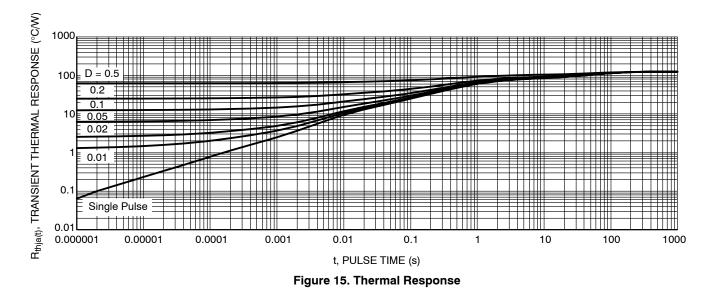


#### **TYPICAL PERFORMANCE CURVES**



#### **TYPICAL PERFORMANCE CURVES**





#### Table 1. ORDERING INFORMATION

Part Number	Marking (XX)	Package	Shipping <sup>†</sup>
NTGS4141NT1	S4	TSOP-6	3000 / Tape & Reel
NTGS4141NT1G	S4	TSOP-6 (Pb-Free)	3000 / Tape & Reel
NVGS4141NT1G	VS4	TSOP-6 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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TSOP-6		PAGE 1 OF 1		
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